













TPS62240, TPS62242, TPS62243

SLVS762C -JUNE 2007-REVISED JULY 2015

TPS6224x 2.25-MHz 300-mA Step-Down Converter in 2 x 2 WSON and SOT Package

Features

- High Efficiency Greater Than 94%
- Output Current up to 300 mA
- VIN Range from 2 V to 6 V for Li-ion Batteries With Extended Voltage Range
- 2.25-MHz Fixed-Frequency Operation
- Power Save Mode at Light Load Currents
- Output Voltage Accuracy in PWM Mode ±1.5%
- Adjustable Output Voltage from 0.6 V to VIN
- Typical 15-µA Quiescent Current
- 100% Duty Cycle for Lowest Dropout
- Available in a SOT (5) and 2-mm × 2-mm × 0.8mm WSON (6) Package
- Allows <1-mm Solution Height

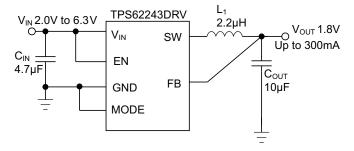
Applications

- Bluetooth™ Headsets
- Mobile Phones, Smart Phones
- **WLAN**
- Low Power DSP Supplies
- Portable Media Players
- **Digital Cameras**

Description

TPS6224x device is a highly efficient synchronous step-down DC-DC converter. The device provides up to 300-mA output current from a single Li-Ion cell and is ideal for battery powered portable applications like mobile phones and other portable equipment.

Typical Application Schematic



With an wide input voltage range of 2 V to 6 V, the device also supports two- and three-cell alkaline, 3.3-V and 5-V input voltage rails.

The TPS6224x operates at 2.25-MHz fixed switching frequency and enters power save mode operation at light load currents to maintain high efficiency over the entire load current range.

The power save mode is optimized for low output voltage ripple. For low-noise applications, the device can be forced into fixed-frequency pulse width modulation (PWM) mode by pulling the MODE pin high. In shutdown mode, the current consumption is reduced to less than 1 µA. The TPS6224x allows the use of small inductors and capacitors to achieve a small solution size.

The TPS6224x operates over a free-air temperature range of -40°C to 85°C. The device is available in a 5-pin SOT and a 6-pin 2-mm × 2-mm WSON package.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)	
TD00004	WSON (6)	2.00 mm × 2.00 mm	
TPS6224x	SOT (5)	2.90 mm × 1.60 mm	

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Efficiency vs Output Current

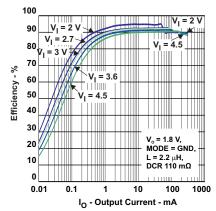




Table of Contents

1	Features 1		8.4 Device Functional Modes	8
2	Applications 1	9	Application and Implementation	10
3	Description 1		9.1 Application Information	10
4	Revision History2		9.2 Typical Application	10
5	Device Options		9.3 System Examples	17
6	Pin Configuration and Functions	10	Power Supply Recommendations	17
7	Specifications	11	Layout	18
•	7.1 Absolute Maximum Ratings		11.1 Layout Guidelines	18
	7.2 ESD Ratings		11.2 Layout Examples	18
	7.3 Recommended Operating Conditions	12	Device and Documentation Support	19
	7.4 Thermal Information		12.1 Device Support	19
	7.5 Electrical Characteristics		12.2 Related Links	19
	7.6 Typical Characteristics		12.3 Community Resources	19
8	Detailed Description 7		12.4 Trademarks	19
٠	8.1 Overview		12.5 Electrostatic Discharge Caution	19
	8.2 Functional Block Diagram		12.6 Glossary	19
	8.3 Feature Description	13	Mechanical, Packaging, and Orderable Information	19

4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Submit Documentation Feedback

Copyright © 2007–2015, Texas Instruments Incorporated

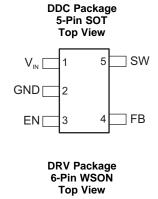


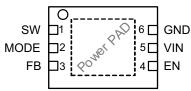
5 Device Options

PART NUMBER (1)	OUTPUT VOLTAGE ⁽²⁾	
TPS62240	adjustable	
TPS62240	adjustable	
TPS62242	1.2 V fixed output voltage	
TPS62243 1.8 V fixed output voltage		

- (1) The DDC (SOT 5 pin) and DRV (WSON 6 pin) packages are available in tape on reel. Add R suffix to order quantities of 3000 parts per reel.
- (2) Contact TI for other fixed output voltage options.

6 Pin Configuration and Functions





Pin Functions

	PIN		1/0	DESCRIPTION
NAME	WSON	SOT	1/0	DESCRIPTION
EN	4	3	I	This is the enable pin of the device. Pulling this pin to low forces the device into shutdown mode. Pulling this pin to high enables the device. This pin must be terminated.
GND	6	2	PWR	GND supply pin.
FB	3	4	I	Feedback pin for the internal regulation loop. Connect the external resistor divider to this pin. In case of fixed output voltage option, connect this pin directly to the output capacitor.
MODE	2	_	-	This pin is only available at WSON package option. MODE pin = High forces the device to operate in fixed-frequency PWM mode. MODE pin = Low enables the power save mode with automatic transition from PFM mode to fixed-frequency PWM mode.
sw	1	5	0	This is the switch pin and is connected to the internal MOSFET switches. Connect the inductor to this terminal.
VIN	5	1	PWR	V _{IN} power supply pin.

Copyright © 2007–2015, Texas Instruments Incorporated



7 Specifications

7.1 Absolute Maximum Ratings

Over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
V_{IN}	Input voltage (2)	-0.3	7	V
	Voltage at EN, MODE	-0.3	V _{IN} +0.3, ≤7	V
	Voltage on SW	-0.3	7	V
	Peak output current	Intern	ally limited	Α
T_{J}	Maximum operating junction temperature	-40	125	°C
T _{stg}	Storage temperature	-65	150	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute—maximum—rated conditions for extended periods may affect device reliability.

7.2 ESD Ratings

			VALUE	UNIT
		Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins (2)	±2000	
V _(ESD)	Electrostatic discharge ⁽¹⁾	Charged device model (CDM), per JEDEC specification JESD22-C101, all pins (3)	±1000	V

⁽¹⁾ The human body model is a 100-pF capacitor discharged through a 1.5-k Ω resistor into each pin.

7.3 Recommended Operating Conditions

Over operating free-air temperature range (unless otherwise noted)

		MIN	NOM I	MAX	UNIT
V_{IN}	Supply voltage, VIN	2		6	V
	Output voltage for adjustable voltage	0.6		V_{IN}	V
T_A	Operating ambient temperature	-40		85	°C
T_{J}	Operating junction temperature	-40		125	°C

7.4 Thermal Information

		TPS		
	THERMAL METRIC ⁽¹⁾	DRV [WSON]	DDC [SOT]	UNIT
		6 PINS	5 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	67.8	226.9	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	88.5	40.7	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	37.2	48.8	°C/W
ΨЈТ	Junction-to-top characterization parameter	2.0	0.5	°C/W
ΨЈВ	Junction-to-board characterization parameter	37.6	48.1	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	7.9	N/A	°C/W

For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.

Product Folder Links: TPS62240 TPS62242 TPS62243

⁽²⁾ All voltage values are with respect to network ground terminal.

⁽²⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

³⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



7.5 Electrical Characteristics

Over full operating ambient temperature range, typical values are at T_A = 25°C. Unless otherwise noted, specifications apply for condition V_{IN} = EN = 3.6 V. External components C_{IN} = 4,7 μF 0603, C_{OUT} = 10 μF 0603, L = 2.2 μH , refer to parameter

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
SUPPLY					·	
V _{IN}	Input voltage range		2		6	V
	Outside some of	2.3 V ≤ V _{IN} ≤ 6 V			300	A
I _{OUT}	Output current	$2 \text{ V} \leq \text{V}_{\text{IN}} \leq 2.3 \text{ V}$			150	mA
		I _{OUT} = 0 mA. PFM mode enabled (MODE = GND) device not switching		15		
I_Q	Operating quiescent current	I_{OUT} = 0 mA. PFM mode enabled (MODE = GND) device switching, V_{OUT} = 1.8 V, ⁽¹⁾		18.5		μA
		I_{OUT} = 0 mA, switching with no load (MODE = V_{IN}), PWM operation , V_{OUT} = 1.8 V, V_{IN} = 3 V		3.8		mA
I_{SD}	Shutdown current	EN = GND		0.1	1	μΑ
UVLO	Undervoltage lockout threshold	Falling		1.85		V
OVLO	Ondervoltage lockout tilleshold	Rising		1.95		v
ENABLE,	MODE					
V_{IH}	High level input voltage, EN, MODE	$2 \text{ V} \leq \text{V}_{\text{IN}} \leq 6 \text{ V}$	1		V_{IN}	V
V_{IL}	Low level input voltage, EN, MODE	$2 \text{ V} \leq \text{V}_{\text{IN}} \leq 6 \text{ V}$	0		0.4	V
I _{IN}	Input bias current, EN, MODE	EN, MODE = GND or V_{IN}		0.01	1	μΑ
POWER S	WITCH					
D	High-side MOSFET ON-resistance	V _{IN} = V _{GS} = 3.6 V, T _A = 25°C		240	480	mΩ
R _{DS(on)}	Low-side MOSFET ON-resistance			180	380	11122
I _{LIMF}	Forward current-limit MOSFET high- side and low-side	V _{IN} = V _{GS} = 3.6 V	0.56	0.7	0.84	Α
TSD	Thermal shutdown	Increasing junction temperature		140		°C
	Thermal shutdown hysteresis	Decreasing junction temperature		20		°C
OSCILLAT	TOR					
f_{SW}	Oscillator frequency	2 V ≤ V _{IN} ≤ 6 V	2	2.25	2.5	MHz
OUTPUT						
V_{OUT}	Adjustable output voltage range		0.6		V_{IN}	V
V _{REF}	Reference voltage			600		mV
	Feedback voltage	MODE = V_{IN} , PWM operation, 2 V \leq V_{IN} \leq 6 V, in fixed output voltage versions $V_{FB} = V_{OUT}$, see $^{(2)}$	-1.5%	0%	1.5%	
V_{FB}	Feedback voltage PFM mode	MODE = GND, device in PFM mode		0%		
	Load regulation	PWM mode		-0.5		%/A
t _{Start Up}	Start-up Time	Time from active EN to reach 95% of V _{OUT} nominal		500		μs
t _{Ramp}	V _{OUT} ramp-up time	Time to ramp from 5% to 95% of V _{OUT}		250		μs
I _{lkg}	Leakage current into SW pin	$V_{IN} = 3.6 \text{ V}, V_{IN} = V_{OUT} = V_{SW}, EN = GND,^{(3)}$		0.1	1	μA

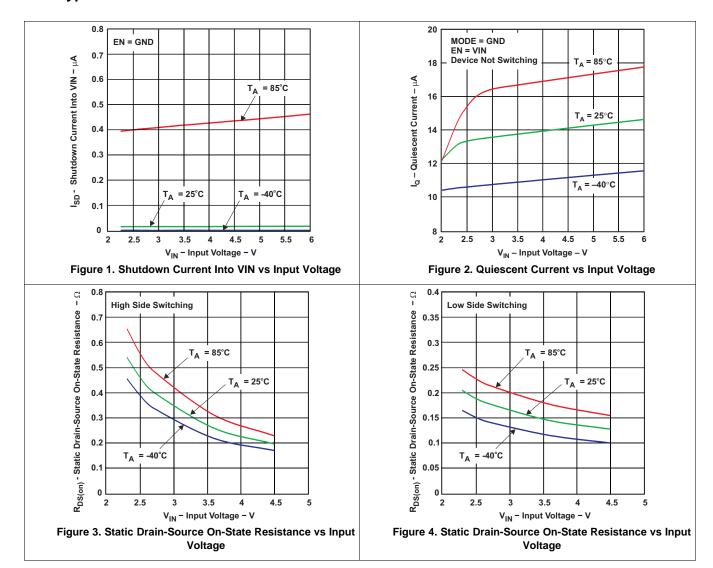
See the parameter measurement information.

⁽²⁾

For $V_{\text{IN}} = V_{\text{OUT}} + 0.6$. In fixed output voltage versions, the internal resistor divider network is disconnected from FB pin.



7.6 Typical Characteristics





8 Detailed Description

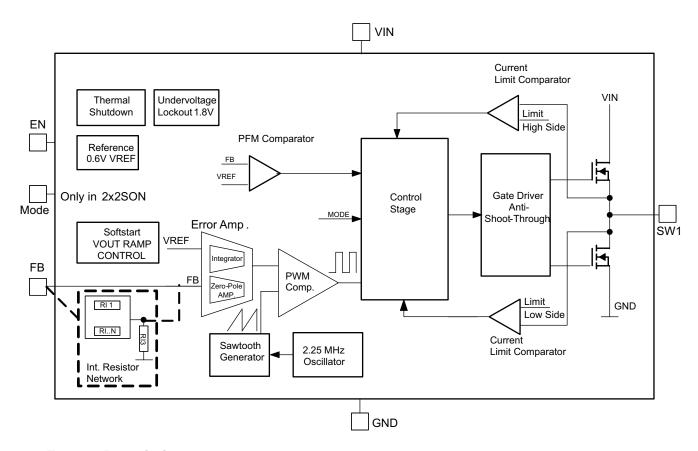
8.1 Overview

The TPS6224x step-down converter operates with typically 2.25-MHz fixed-frequency pulse width modulation (PWM) at moderate to heavy load currents. At light load currents, the converter can automatically enter power save mode and operates then in pulse frequency modulation (PFM) mode.

During PWM operation, the converter uses a unique fast response voltage mode control scheme with input voltage feed-forward to achieve good line and load regulation, allowing the use of small ceramic input and output capacitors. At the beginning of each clock cycle initiated by the clock signal, the high-side MOSFET switch is turned on. The current then flows from the input capacitor through the high-side MOSFET switch through the inductor to the output capacitor and load. During this phase, the current ramps up until the PWM comparator trips and the control logic turns off the switch. The current-limit comparator also turns off the switch if the current limit of the high-side MOSFET switch is exceeded. After a dead time preventing shoot-through current, the low-side MOSFET rectifier is turned on and the inductor current ramps down. The current then flows from the inductor to the output capacitor and to the load. It returns back to the inductor through the low-side MOSFET rectifier.

The next cycle is initiated by the clock signal again turning off the low-side MOSFET rectifier and turning on the high-side MOSFET switch.

8.2 Functional Block Diagram



8.3 Feature Description

8.3.1 Undervoltage Lockout

The undervoltage lockout circuit prevents the device from malfunctioning at low input voltages and from excessive discharge of the battery and disables the output stage of the converter. The undervoltage lockout threshold is typically 1.85 V with falling $V_{\rm IN}$.

Copyright © 2007–2015, Texas Instruments Incorporated



Feature Description (continued)

8.3.2 Mode Selection

The MODE pin allows mode selection between forced PWM mode and power save mode.

Connecting this pin to GND enables the power save mode with an automatic transition between PWM and PFM mode. Pulling the MODE pin high forces the converter to operate in fixed-frequency PWM mode even at light load currents. This allows simple filtering of the switching frequency for noise sensitive applications. In this mode, the efficiency is lower compared to the power save mode during light loads.

The condition of the MODE pin can be changed during operation and allows efficient power management by adjusting the operation mode of the converter to the specific system requirements.

8.3.3 **Enable**

The device is enabled by setting the EN pin to high. During the start up time $t_{Start\ Up}$, the internal circuits are settled and the soft start circuit is activated. The EN input can be used to control power sequencing in a system with various DC-DC converters. The EN pin can be connected to the output of another converter, to drive the EN pin high and getting a sequencing of supply rails. With EN pin = GND, the device enters shutdown mode in which all circuits are disabled. In fixed output voltage versions, the internal resistor divider network is then disconnected from FB pin.

8.3.4 Thermal Shutdown

As soon as the junction temperature, T_J , exceeds 140°C (typical) the device goes into thermal shutdown. In this mode, the high-side and low-side MOSFETs are turned off. The device continues its operation when the junction temperature falls below the thermal shutdown hysteresis.

8.4 Device Functional Modes

8.4.1 Soft Start

The TPS6224x has an internal soft-start circuit that controls the ramp up of the output voltage. The output voltage ramps up from 5% to 95% of its nominal value within typical 250 µs. This limits the inrush current in the converter during ramp up and prevents possible input voltage drops when a battery or high impedance power source is used. The soft-start circuit is enabled within the start-up time, t_{Start up}.

8.4.2 Power Save Mode

The power save mode is enabled with MODE pin set to low level. If the load current decreases, the converter will enter power save mode operation automatically. During power save mode, the converter skips switching and operates with reduced frequency in PFM mode with a minimum quiescent current to maintain high efficiency.

The transition from PWM mode to PFM mode occurs once the inductor current in the low-side MOSFET switch becomes zero, which indicates discontinuous conduction mode.

During the power save mode, the output voltage is monitored with a PFM comparator. As the output voltage falls below the PFM comparator threshold of V_{OUT} nominal, the device starts a PFM current pulse. The high-side MOSFET switch will turn on, and the inductor current ramps up. After the on-time expires, the switch is turned off and the low-side MOSFET switch is turned on until the inductor current becomes zero.

The converter effectively delivers a current to the output capacitor and the load. If the load is below the delivered current, the output voltage will rise. If the output voltage is equal to or greater than the PFM comparator threshold, the device stops switching and enters a sleep mode with typical 15-µA current consumption.

If the output voltage is still below the PFM comparator threshold, a sequence of further PFM current pulses are generated until the PFM comparator threshold is reached. The converter starts switching again once the output voltage drops below the PFM comparator threshold.

Submit Documentation Feedback

Copyright © 2007–2015, Texas Instruments Incorporated



Device Functional Modes (continued)

With a fast single-threshold comparator, the output voltage ripple during PFM mode operation can be kept to a minimum. The PFM pulse is time controlled, which allows to modify the charge transferred to the output capacitor by the value of the inductor. The resulting PFM output voltage ripple and PFM frequency both depend on the size of the output capacitor and the inductor value. Increasing output capacitor values and inductor values will minimize the output ripple. The PFM frequency decreases with smaller inductor values and increases with larger values.

If the output current cannot be supported in PFM mode, the device exits PFM mode and enters PWM mode. The power save mode can be disabled through the MODE pin set to high. The converter will then operate in fixedfrequency PWM mode.

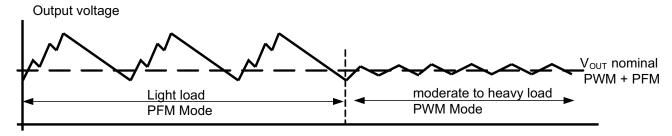


Figure 5. Power Save Mode

8.4.3 100% Duty Cycle Low Dropout Operation

The device starts to enter 100% duty cycle mode once the input voltage comes close to the nominal output voltage. To maintain the output voltage, the high-side MOSFET switch is turned on 100% for one or more cycles.

With further decreasing V_{IN} the high-side MOSFET switch is turned on completely. In this case the converter offers a low input-to-output voltage difference. This is particularly useful in battery-powered applications to achieve longest operation time by taking full advantage of the entire battery voltage range.

The minimum input voltage to maintain regulation depends on the load current and output voltage, and can be calculated as:

 $V_{IN}min = V_{OUT}max + I_{OUT}max \times R_{DS(on)}max + R_{L}$

where

- I_{OUT}max = Maximum output current plus inductor ripple current
- $R_{DS(on)}$ max = Maximum P-channel switch $R_{DS(on)}$
- $R_1 = DC$ resistance of the inductor
- V_{OUT}max = Nominal output voltage plus maximum output voltage tolerance

8.4.4 Short-Circuit Protection

The high-side and low-side MOSFET switches are short-circuit protected with maximum switch current equal to I_{I IMF}. The current in the switches is monitored by current-limit comparators. Once the current in the high-side MOSFET switch exceeds the threshold of its current-limit comparator, it turns off and the low-side MOSFET switch is activated to ramp down the current in the inductor and high-side MOSFET switch. The high-side MOSFET switch can only turn on again, once the current in the low-side MOSFET switch has decreased below the threshold of its current-limit comparator.

Copyright © 2007-2015, Texas Instruments Incorporated

(1)

9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The TPS6224x device is a high-efficiency synchronous step-down DC-DC converter featuring power save mode or 2.25-MHz fixed-frequency operation.

9.2 Typical Application

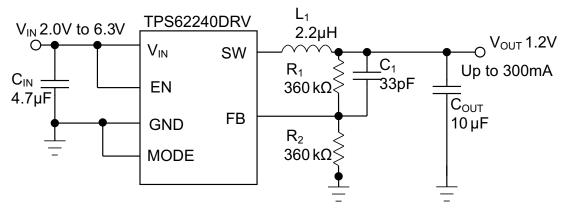


Figure 6. TPS62240DRV Adjustable 1.2 V

9.2.1 Design Requirements

The device operates over an input voltage range from 2 V to 6 V. The output voltage is adjustable using an external feedback divider.

9.2.2 Detailed Design Procedure

Table 1 shows the list of components for the Application Curves.

Table 1. List of Components

COMPONENT REFERENCE	PART NUMBER	MANUFACTURER	VALUE		
C _{IN}	GRM188R60J475K	Murata	4.7 µF, 6.3 V. X5R Ceramic		
C _{OUT}	GRM188R60J106M	Murata	10 μF, 6.3 V. X5R Ceramic		
C ₁		Murata	22 pF, COG Ceramic		
L ₁	LPS3015	Coilcraft	2.2 μH, 110 mΩ		
R ₁ , R ₂	Values depending on the programmed output voltage				

9.2.2.1 Output Voltage Setting

The output voltage can be calculated to:

$$V_{OUT} = V_{REF} \times \left(1 + \frac{R_1}{R_2}\right)_{\text{with an internal reference voltage } V_{REF} \text{ typical 0.6 V.}}$$
(2)

To minimize the current through the feedback divider network, R_2 should be 180 k Ω or 360 k Ω . The sum of R_1 and R_2 should not exceed approximately 1 M Ω , to keep the network robust against noise.

Submit Documentation Feedback

Copyright © 2007–2015, Texas Instruments Incorporated



An external feedforward capacitor C_1 is required for optimum load transient response. The value of C_1 should be in the range from 22 pF to 33 pF.

Route the FB line away from noise sources, such as the inductor or the SW line.

9.2.2.2 Output Filter Design (Inductor and Output Capacitor)

The TPS6224x is designed to operate with inductors in the range of 1.5 μ H to 4.7 μ H and with output capacitors in the range of 4.7 μ F to 22 μ F. The device is optimized for operation with a 2.2- μ H inductor and 10- μ F output capacitor.

Larger or smaller inductor values can be used to optimize the performance of the device for specific operation conditions. For stable operation, the L and C values of the output filter may not fall below 1-µH effective inductance and 3.5-µF effective capacitance. Selecting larger capacitors is less critical because the corner frequency of the L-C filter moves to lower frequencies with fewer stability problems.

9.2.2.2.1 Inductor Selection

The inductor value has a direct effect on the ripple current. The selected inductor must be rated for its DC resistance and saturation current. The inductor ripple current (ΔI_L) decreases with higher inductance and increases with higher V_{IN} or V_{OUT} .

The inductor selection also has an impact on the output voltage ripple in the PFM mode. Higher inductor values will lead to lower output voltage ripple and higher PFM frequency, and lower inductor values will lead to a higher output voltage ripple but lower PFM frequency.

Equation 3 calculates the maximum inductor current in PWM mode under static load conditions. The saturation current of the inductor should be rated higher than the maximum inductor current as calculated with Equation 4. This is recommended because during heavy load transients the inductor current will rise above the calculated value.

$$\Delta I_{L} = V_{OUT} \times \frac{1 - \frac{V_{OUT}}{V_{IN}}}{L \times f}$$

$$I_{Lmax} = I_{OUTmax} + \frac{\Delta I_{L}}{2}$$
(3)

where

- f = Switching frequency (2.25-MHz typical)
- L = Inductor value
- ΔI_L = Peak-to-peak inductor ripple current

A more conservative approach is to select the inductor current rating just for the maximum switch current limit I_{LIME} of the converter.

Accepting larger values of ripple current allows the use of low inductance values, but results in higher output voltage ripple, greater core losses, and lower output current capability.

The total losses of the coil have a strong impact on the efficiency of the DC-DC conversion and consist of both the losses in the DC resistance ($R_{(DC)}$) and the following frequency-dependent components:

- The losses in the core material (magnetic hysteresis loss, especially at high switching frequencies)
- Additional losses in the conductor from the skin effect (current displacement at high frequencies)
- Magnetic field losses of the neighboring windings (proximity effect)
- Radiation losses

Copyright © 2007–2015, Texas Instruments Incorporated

Table	2	l ist	Ωf	Indi	ictors

DIMENSIONS (mm ³)	INDUCTANCE (µH)	INDUCTOR TYPE	SUPPLIER
2.5 × 2 × 1	2	MIPS2520D2R2	FDK
2.5 × 2 × 1.2	2	MIPSA2520D2R2	FDK
2.5 × 2 × 1	2.2	KSLI-252010AG2R2	Hitachi Metals
2.5 × 2 × 1.2	2.2	LQM2HPN2R2MJ0L	Murata
3 × 3 × 1.4	2.2	LPS3015	Coilcraft

9.2.2.2.2 Output Capacitor Selection

The advanced fast-response voltage mode control scheme of the TPS6224x allows the use of tiny ceramic capacitors. Ceramic capacitors with low ESR values have the lowest output voltage ripple and are recommended. The output capacitor requires either an X7R or X5R dielectric. Y5V and Z5U dielectric capacitors, aside from their wide variation in capacitance overtemperature, become resistive at high frequencies.

At nominal load current, the device operates in PWM mode and the RMS ripple current is calculated as:

$$I_{RMSC_{OUT}} = V_{OUT} \times \frac{1 - \frac{V_{OUT}}{V_{IN}}}{L \times f} \times \frac{1}{2 \times \sqrt{3}}$$
(5)

At nominal load current, the device operates in PWM mode and the overall output voltage ripple is the sum of the voltage spike caused by the output capacitor ESR plus the voltage ripple caused by charging and discharging the output capacitor:

$$\Delta V_{OUT} = V_{OUT} \times \frac{1 - \frac{V_{OUT}}{V_{IN}}}{L \times f} \times \left(\frac{1}{8 \times C_{OUT} \times f} + ESR\right)$$
(6)

At light load currents, the converter operates in power save mode and the output voltage ripple depends on the output capacitor and inductor value. Larger output capacitor and inductor values minimize the voltage ripple in PFM mode and tighten DC output accuracy in PFM mode.

9.2.2.2.3 Input Capacitor Selection

The buck converter has a natural pulsating input current; therefore, a low ESR input capacitor is required for best input voltage filtering, and minimizing the interference with other circuits caused by high input voltage spikes. For most applications, a 4.7- μ F to 10- μ F ceramic capacitor is recommended. Because ceramic capacitors lose up to 80% of their initial capacitance at 5 V, it is recommended that a 10- μ F input capacitor be used for input voltages greater than 4.5 V. The input capacitor can be increased without any limit for better input voltage filtering.

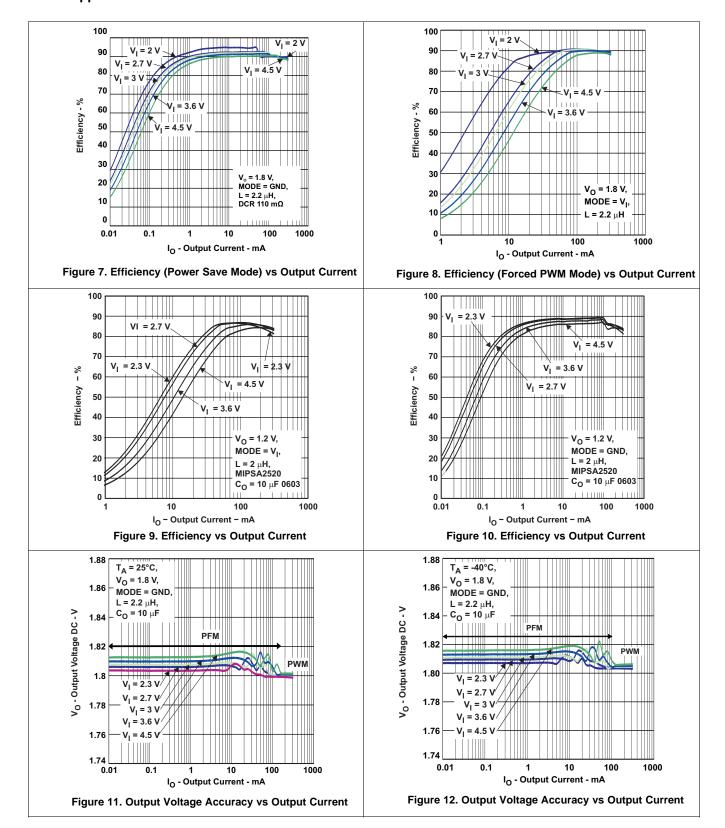
Take care when using only small ceramic input capacitors. When a ceramic capacitor is used at the input, and the power is being supplied through long wires, such as from a wall adapter, a load step at the output, or V_{IN} step on the input, can induce ringing at the VIN pin. The ringing can couple to the output and be mistaken as loop instability, or could even damage the part by exceeding the maximum ratings

Table 3. List of Capacitors

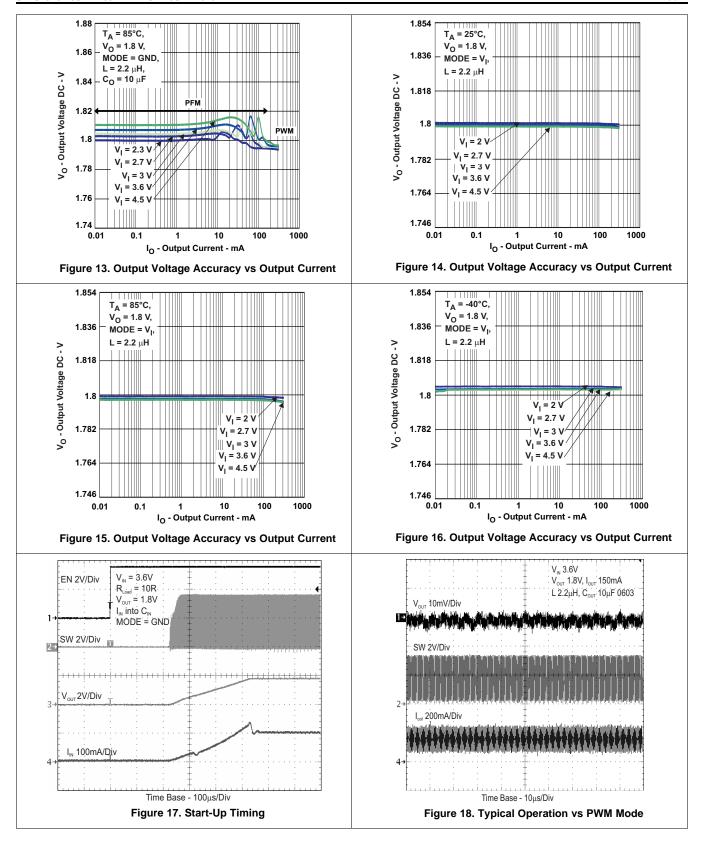
CAPACITANCE	TYPE	SIZE	SUPPLIER
4.7 µF	GRM188R60J475K	0603: $1.6 \times 0.8 \times 0.8 \text{ mm}^3$	Murata
10 μF	GRM188R60J106M69D	0603: 1.6 × 0.8 × 0.8 mm ³	Murata



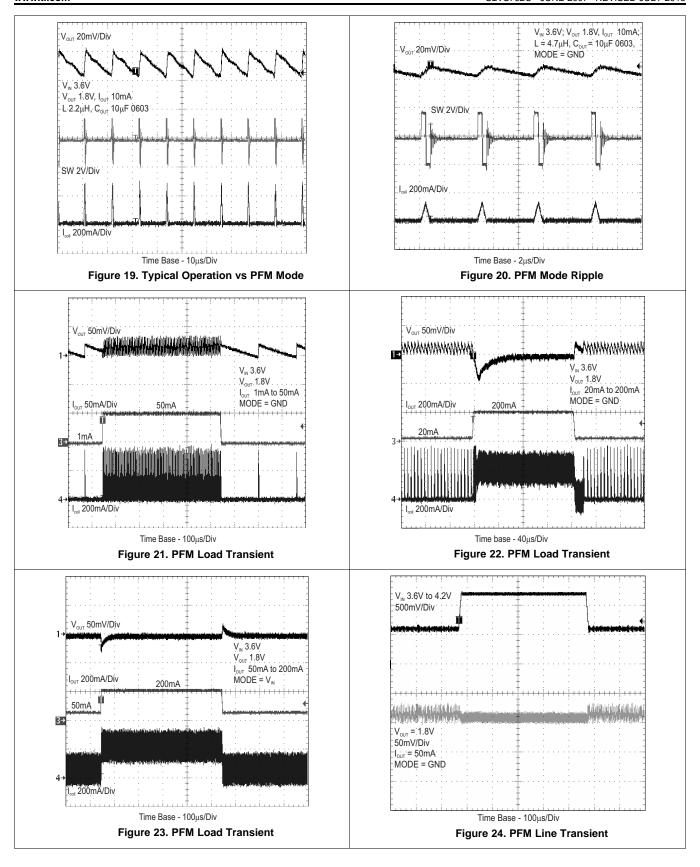
9.2.3 Application Curves



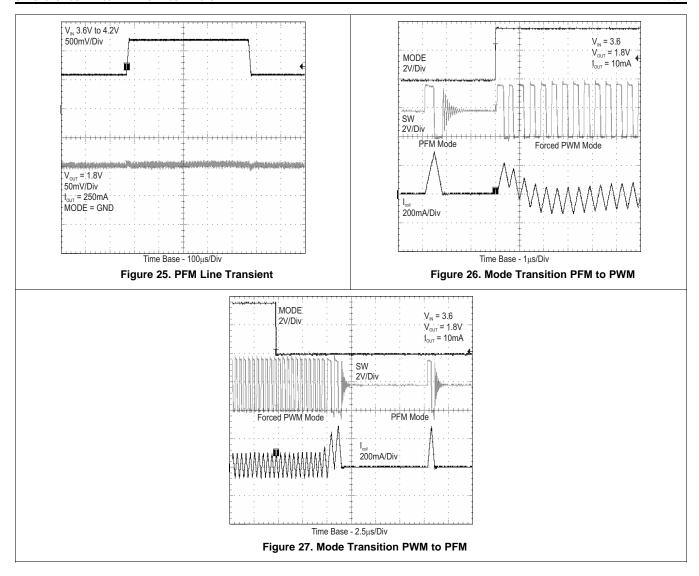














9.3 System Examples

9.3.1 TPS62240, Adjustable Output Voltage 1.8 V

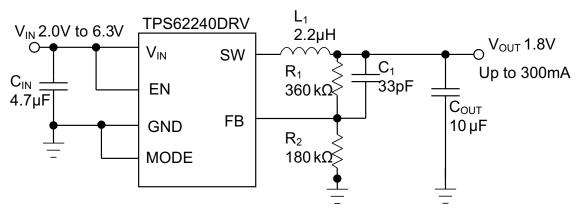


Figure 28. TPS62240DRV 1.8 V

9.3.2 TPS62243, Fixed Output Voltage 1.8 V

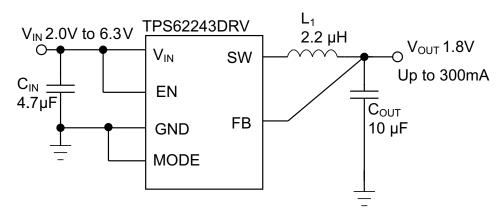


Figure 29. TPS62243 Fixed 1.8 V

10 Power Supply Recommendations

The TPS6224x device has no special requirements for its input power supply. The input power supply output current must be rated according to the supply voltage, output voltage, and output current of the TPS6224x.



11 Layout

11.1 Layout Guidelines

As for all switching power supplies, the layout is an important step in the design. Proper function of the device demands careful attention to PCB layout. Care must be taken in board layout to get the specified performance. If the layout is not carefully done, the regulator could show poor line and/or load regulation, and additional stability issues as well as EMI problems. It is critical to provide a low inductance, impedance ground path. Therefore, use wide and short traces for the main current paths. The input capacitor should be placed as close as possible to the IC pins as well as the inductor and output capacitor.

Connect the GND pin of the device to the PowerPAD™ land of the PCB and use this pad as a star point. Use a common power GND node and a different node for the signal GND to minimize the effects of ground noise. Connect these ground nodes together to the PowerPAD land (star point) underneath the IC. Keep the common path to the GND pin, which returns the small signal components, and the high current of the output capacitors as short as possible to avoid ground noise. The FB line should be connected right to the output capacitor and routed away from noisy components and traces (for example, the SW line).

11.2 Layout Examples

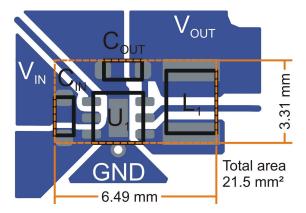


Figure 30. Suggested Layout for Fixed Output Voltage Options

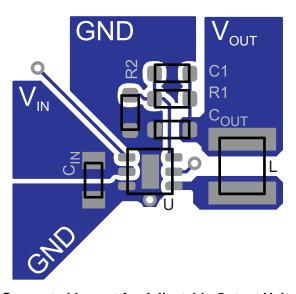


Figure 31. Suggested Layout for Adjustable Output Voltage Version

Submit Documentation Feedback

Copyright © 2007–2015, Texas Instruments Incorporated



12 Device and Documentation Support

12.1 Device Support

12.1.1 Third-Party Products Disclaimer

TI'S PUBLICATION OF INFORMATION REGARDING THIRD-PARTY PRODUCTS OR SERVICES DOES NOT CONSTITUTE AN ENDORSEMENT REGARDING THE SUITABILITY OF SUCH PRODUCTS OR SERVICES OR A WARRANTY, REPRESENTATION OR ENDORSEMENT OF SUCH PRODUCTS OR SERVICES, EITHER ALONE OR IN COMBINATION WITH ANY TI PRODUCT OR SERVICE.

12.2 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 4. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY		
TPS62240	Click here	Click here	Click here	Click here	Click here		
TPS62242	Click here	Click here	Click here	Click here	Click here		
TPS62243	Click here	Click here	Click here	Click here	Click here		

12.3 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community T's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

12.4 Trademarks

PowerPAD, E2E are trademarks of Texas Instruments. Bluetooth is a trademark of Bluetooth SIG, Inc.

All other trademarks are the property of their respective owners.

12.5 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.6 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Copyright © 2007–2015, Texas Instruments Incorporated





28-Feb-2017

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
TPS62240DDCR	ACTIVE	SOT-23-THIN	DDC	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ВУО	Samples
TPS62240DDCRG4	ACTIVE	SOT-23-THIN	DDC	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ВУО	Sample
TPS62240DDCT	ACTIVE	SOT-23-THIN	DDC	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ВУО	Sample
TPS62240DDCTG4	ACTIVE	SOT-23-THIN	DDC	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ВУО	Sample
TPS62240DRVR	ACTIVE	WSON	DRV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	BYJ	Sample
TPS62240DRVRG4	ACTIVE	WSON	DRV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	BYJ	Sample
TPS62240DRVT	ACTIVE	WSON	DRV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	BYJ	Sample
TPS62240DRVTG4	ACTIVE	WSON	DRV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	BYJ	Sample
TPS62242DRVR	ACTIVE	WSON	DRV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	CCY	Sample
TPS62242DRVRG4	ACTIVE	WSON	DRV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	CCY	Sample
TPS62242DRVT	ACTIVE	WSON	DRV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	CCY	Sample
TPS62242DRVTG4	ACTIVE	WSON	DRV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	CCY	Sample
TPS62243DRVR	ACTIVE	WSON	DRV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	CBQ	Sample
TPS62243DRVT	ACTIVE	WSON	DRV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	CBQ	Sample
TPS62243DRVTG4	ACTIVE	WSON	DRV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	CBQ	Sample

⁽¹⁾ The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.



www.ti.com

PACKAGE OPTION ADDENDUM

28-Feb-2017

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF TPS62242:

Automotive: TPS62242-Q1

NOTE: Qualified Version Definitions:

Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

PACKAGE MATERIALS INFORMATION

www.ti.com 3-Aug-2017

TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS62240DDCR	SOT- 23-THIN	DDC	5	3000	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS62240DDCT	SOT- 23-THIN	DDC	5	250	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS62240DRVR	WSON	DRV	6	3000	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS62240DRVT	WSON	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS62242DRVR	WSON	DRV	6	3000	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS62242DRVT	WSON	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS62243DRVR	WSON	DRV	6	3000	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS62243DRVT	WSON	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2

www.ti.com 3-Aug-2017

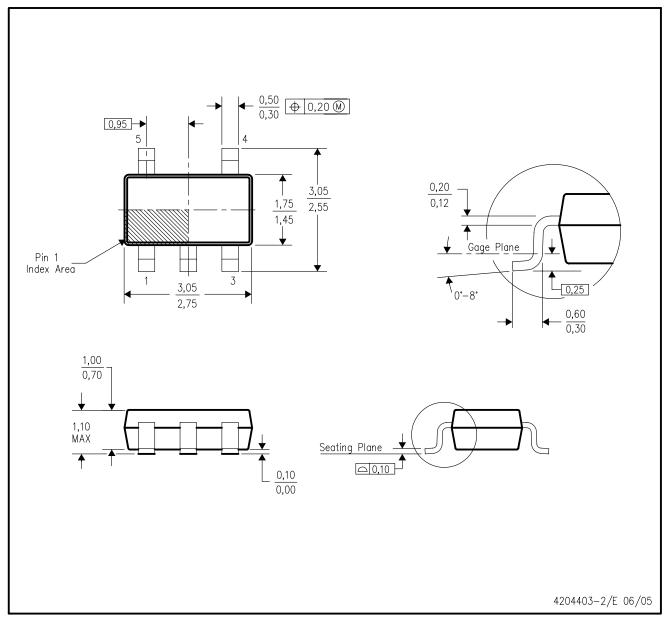


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS62240DDCR	SOT-23-THIN	DDC	5	3000	203.0	203.0	35.0
TPS62240DDCT	SOT-23-THIN	DDC	5	250	203.0	203.0	35.0
TPS62240DRVR	WSON	DRV	6	3000	203.0	203.0	35.0
TPS62240DRVT	WSON	DRV	6	250	203.0	203.0	35.0
TPS62242DRVR	WSON	DRV	6	3000	203.0	203.0	35.0
TPS62242DRVT	WSON	DRV	6	250	203.0	203.0	35.0
TPS62243DRVR	WSON	DRV	6	3000	203.0	203.0	35.0
TPS62243DRVT	WSON	DRV	6	250	203.0	203.0	35.0

DDC (R-PDSO-G5)

PLASTIC SMALL-OUTLINE



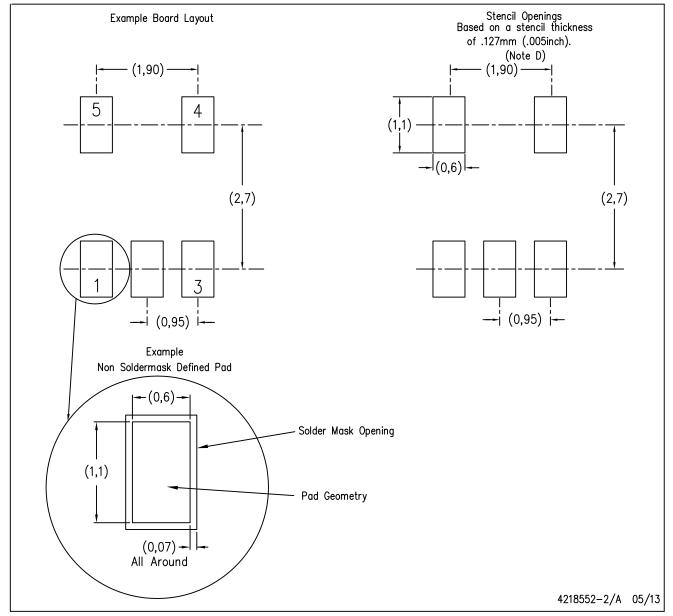
NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion.
- D. Falls within JEDEC MO-193 variation AB (5 pin).



DDC (R-PDSO-G5)

PLASTIC SMALL OUTLINE



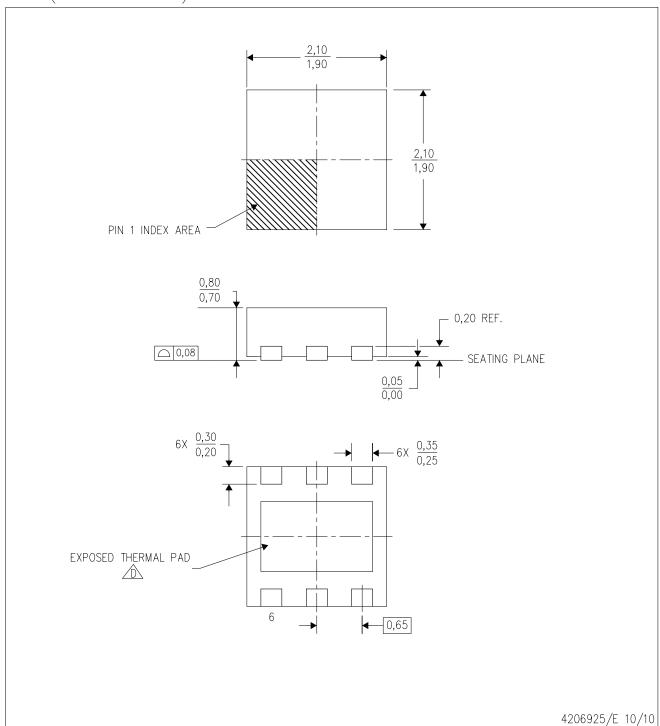
NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



DRV (S-PWSON-N6)

PLASTIC SMALL OUTLINE NO-LEAD



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Small Outline No-Lead (SON) package configuration.

The package thermal pad must be soldered to the board for thermal and mechanical performance. See the Product Data Sheet for details regarding the exposed thermal pad dimensions.



DRV (S-PWSON-N6)

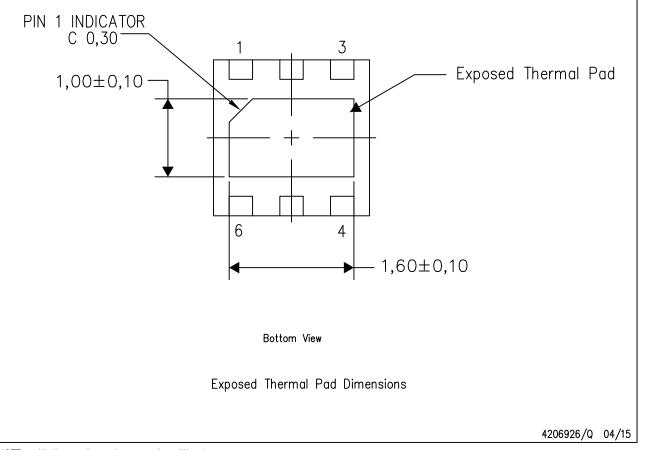
PLASTIC SMALL OUTLINE NO-LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No—Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.

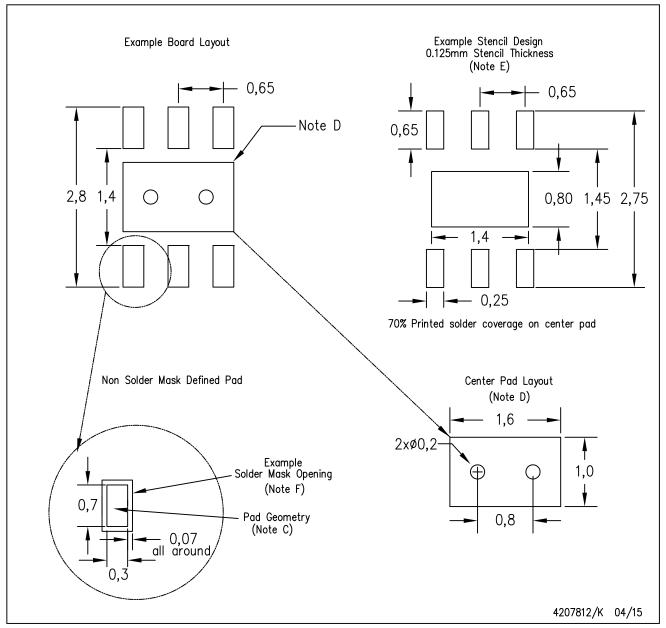


NOTE: All linear dimensions are in millimeters



DRV (S-PWSON-N6)

PLASTIC SMALL OUTLINE NO-LEAD



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com www.ti.com.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for solder mask tolerances.



IMPORTANT NOTICE

Texas Instruments Incorporated (TI) reserves the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete.

TI's published terms of sale for semiconductor products (http://www.ti.com/sc/docs/stdterms.htm) apply to the sale of packaged integrated circuit products that TI has qualified and released to market. Additional terms may apply to the use or sale of other types of TI products and services.

Reproduction of significant portions of TI information in TI data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such reproduced documentation. Information of third parties may be subject to additional restrictions. Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyers and others who are developing systems that incorporate TI products (collectively, "Designers") understand and agree that Designers remain responsible for using their independent analysis, evaluation and judgment in designing their applications and that Designers have full and exclusive responsibility to assure the safety of Designers' applications and compliance of their applications (and of all TI products used in or for Designers' applications) with all applicable regulations, laws and other applicable requirements. Designer represents that, with respect to their applications, Designer has all the necessary expertise to create and implement safeguards that (1) anticipate dangerous consequences of failures, (2) monitor failures and their consequences, and (3) lessen the likelihood of failures that might cause harm and take appropriate actions. Designer agrees that prior to using or distributing any applications that include TI products, Designer will thoroughly test such applications and the functionality of such TI products as used in such applications.

TI's provision of technical, application or other design advice, quality characterization, reliability data or other services or information, including, but not limited to, reference designs and materials relating to evaluation modules, (collectively, "TI Resources") are intended to assist designers who are developing applications that incorporate TI products; by downloading, accessing or using TI Resources in any way, Designer (individually or, if Designer is acting on behalf of a company, Designer's company) agrees to use any particular TI Resource solely for this purpose and subject to the terms of this Notice.

TI's provision of TI Resources does not expand or otherwise alter TI's applicable published warranties or warranty disclaimers for TI products, and no additional obligations or liabilities arise from TI providing such TI Resources. TI reserves the right to make corrections, enhancements, improvements and other changes to its TI Resources. TI has not conducted any testing other than that specifically described in the published documentation for a particular TI Resource.

Designer is authorized to use, copy and modify any individual TI Resource only in connection with the development of applications that include the TI product(s) identified in such TI Resource. NO OTHER LICENSE, EXPRESS OR IMPLIED, BY ESTOPPEL OR OTHERWISE TO ANY OTHER TI INTELLECTUAL PROPERTY RIGHT, AND NO LICENSE TO ANY TECHNOLOGY OR INTELLECTUAL PROPERTY RIGHT OF TI OR ANY THIRD PARTY IS GRANTED HEREIN, including but not limited to any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information regarding or referencing third-party products or services does not constitute a license to use such products or services, or a warranty or endorsement thereof. Use of TI Resources may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

TI RESOURCES ARE PROVIDED "AS IS" AND WITH ALL FAULTS. TI DISCLAIMS ALL OTHER WARRANTIES OR REPRESENTATIONS, EXPRESS OR IMPLIED, REGARDING RESOURCES OR USE THEREOF, INCLUDING BUT NOT LIMITED TO ACCURACY OR COMPLETENESS, TITLE, ANY EPIDEMIC FAILURE WARRANTY AND ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, AND NON-INFRINGEMENT OF ANY THIRD PARTY INTELLECTUAL PROPERTY RIGHTS. TI SHALL NOT BE LIABLE FOR AND SHALL NOT DEFEND OR INDEMNIFY DESIGNER AGAINST ANY CLAIM, INCLUDING BUT NOT LIMITED TO ANY INFRINGEMENT CLAIM THAT RELATES TO OR IS BASED ON ANY COMBINATION OF PRODUCTS EVEN IF DESCRIBED IN TI RESOURCES OR OTHERWISE. IN NO EVENT SHALL TI BE LIABLE FOR ANY ACTUAL, DIRECT, SPECIAL, COLLATERAL, INDIRECT, PUNITIVE, INCIDENTAL, CONSEQUENTIAL OR EXEMPLARY DAMAGES IN CONNECTION WITH OR ARISING OUT OF TI RESOURCES OR USE THEREOF, AND REGARDLESS OF WHETHER TI HAS BEEN ADVISED OF THE POSSIBILITY OF SUCH DAMAGES.

Unless TI has explicitly designated an individual product as meeting the requirements of a particular industry standard (e.g., ISO/TS 16949 and ISO 26262), TI is not responsible for any failure to meet such industry standard requirements.

Where TI specifically promotes products as facilitating functional safety or as compliant with industry functional safety standards, such products are intended to help enable customers to design and create their own applications that meet applicable functional safety standards and requirements. Using products in an application does not by itself establish any safety features in the application. Designers must ensure compliance with safety-related requirements and standards applicable to their applications. Designer may not use any TI products in life-critical medical equipment unless authorized officers of the parties have executed a special contract specifically governing such use. Life-critical medical equipment is medical equipment where failure of such equipment would cause serious bodily injury or death (e.g., life support, pacemakers, defibrillators, heart pumps, neurostimulators, and implantables). Such equipment includes, without limitation, all medical devices identified by the U.S. Food and Drug Administration as Class III devices and equivalent classifications outside the U.S.

TI may expressly designate certain products as completing a particular qualification (e.g., Q100, Military Grade, or Enhanced Product). Designers agree that it has the necessary expertise to select the product with the appropriate qualification designation for their applications and that proper product selection is at Designers' own risk. Designers are solely responsible for compliance with all legal and regulatory requirements in connection with such selection.

Designer will fully indemnify TI and its representatives against any damages, costs, losses, and/or liabilities arising out of Designer's non-compliance with the terms and provisions of this Notice.